MOTORORA031供应商 SEMICONDUCTOR TECHNICAL DATA

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by MRF10031/D

The RF Line **Microwave Long Pulse Power Transistor**

Designed for 960-1215 MHz long or short pulse common base amplifier applications such as JTIDS and Mode-S transmitters.

- Guaranteed Performance @ 960 MHz, 36 Vdc Output Power = 30 Watts Peak Minimum Gain = 9.0 dB Min (9.5 dB Typ)
- 100% Tested for Load Mismatch at All Phase Angles with 10:1 VSWR
- Hermetically Sealed Industry Standard Package
- Silicon Nitride Passivated
- Gold Metallized, Emitter Ballasted for Long Life and Resistance to Metal Migration
- Internal Input Matching for Broadband Operation



30 W (PEAK) 960-1215 MHz **MICROWAVE POWER** TRANSISTOR NPN SILICON



MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage	VCES	55	Vdc	
Collector–Base Voltage (1)	VCBO	55	Vdc	
Emitter-Base Voltage	VEBO	3.5	Vdc	
Collector Current — Continuous (1)	IC	3.0	Adc	
Total Device Dissipation @ T _C = 25°C (1), (2) Derate above 25°C	PD	110 0.625	Watts mW/°C	
Storage Temperature Range	T _{stg}	- 65 to + 200	°C	
Junction Temperature	Тј	200	°C	

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case (3)	R _{θJC}	1.6	°C/W

NOTES:

1. Under pulse RF operating conditions.

2. These devices are designed for RF operation. The total device dissipation rating applies only when the devices are operated as pulsed RF amplifiers.

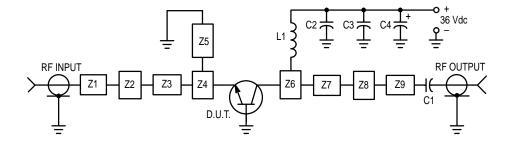
3. Thermal Resistance is determined under specified RF operating conditions by infrared measurement techniques. (Worst case θ_{JC} value measured @ 23% duty cycle)

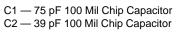




Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•				•
Collector–Emitter Breakdown Voltage ($I_C = 25 \text{ mAdc}, V_{BE} = 0$)	V(BR)CES	55	—	-	Vdc
Collector–Base Breakdown Voltage ($I_C = 25 \text{ mAdc}, I_E = 0$)	V(BR)CBO	55	-	-	Vdc
Emitter–Base Breakdown Voltage (I _E = 5.0 mAdc, I _C = 0)	V(BR)EBO	3.5	-	—	Vdc
Collector Cutoff Current (V_{CB} = 36 Vdc, I _E = 0)	ICBO	—	-	2.0	mAdc
ON CHARACTERISTICS					
DC Current Gain (I _C = 500 mAdc, V_{CE} = 5.0 Vdc)	hFE	20	_	-	-
FUNCTIONAL TESTS (10 µs Pulses @ 50% duty cycle for 3.5 ms	; overall duty cyc	de – 25%)		-	
Common–Base Amplifier Power Gain (V _{CC} = 36 Vdc, P _{out} = 30 W Peak, f = 960 MHz)	G _{PB}	9.0	9.5	-	dB
Collector Efficiency (V _{CC} = 36 Vdc, P _{out} = 30 W Peak, f = 960 MHz)	η	40	45	-	%
Load Mismatch (V _{CC} = 36 Vdc, P _{out} = 30 W Peak, f = 960 MHz, VSWR = 10:1 All Phase Angles)	Ψ	No Degradation in Output Power			

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)





 $C3 - 0.1\,\mu F$

 $C4 - 1000 \,\mu\text{F}$, 50 Vdc, Electrolytic

L1 — 3 Turns #18 AWG, 1/8" ID, 0.18 Long

Z1-Z9 — Microstrip, See Details Board Material - Teflon, Glass Laminate Dielectric Thickness = 0.030" ϵ_{r} = 2.55, 2 Oz. Copper

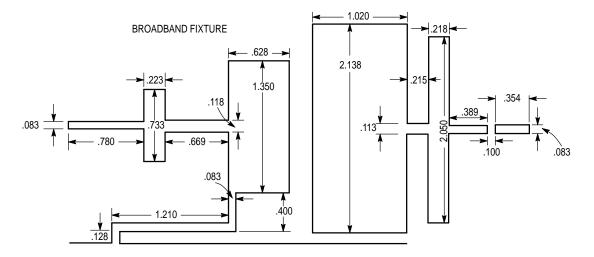
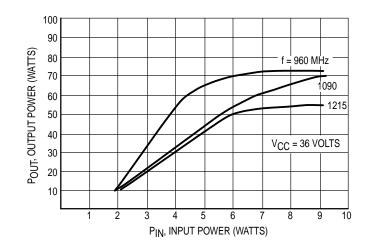
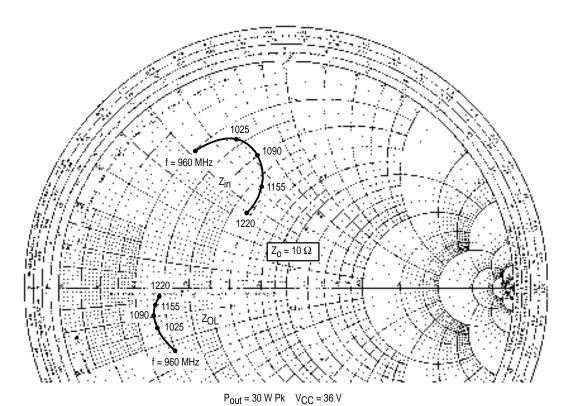


Figure 1. Test Circuit





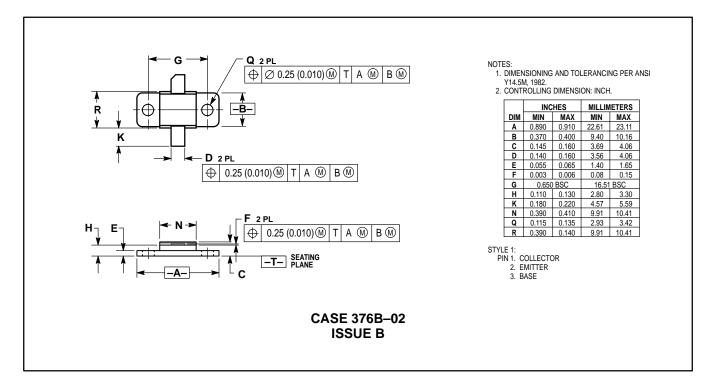


Z _{OL} * Ohms
.9 – j2.35
55 – j1.3
52 – j0.9
.6 – j0.6
.8 – j0.3

$$\label{eq:ZOL} \begin{split} & Z_{OL}{}^{\star} = Conjugate \mbox{ of the optimum load} \\ & impedance \mbox{ into which the device operates at} \\ & a \mbox{ given output power, voltage, and frequency.} \end{split}$$

Figure 3. Series Equivalent Input/Output Impedances

PACKAGE DIMENSIONS



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